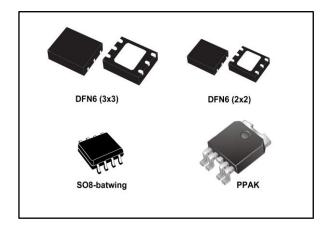


1.2 A low quiescent current LDO with reverse current protection

Datasheet - production data



Features

- Input voltage from 1.6 to 5.5 V
- Very low-dropout voltage (300 mV typ. at 1 A load)
- Low quiescent current (35 μA typ. at no-load, 1 μA max. in off mode)
- Output voltage tolerance: ± 2.0% at 25 °C
- 1.2 A guaranteed output current
- Wide range of output voltages available on request: 0.8 V to 5 V with 50 mV step and adjustable
- Logic-controlled electronic shutdown
- Compatible with ceramic capacitor $C_{\text{OUT}} = 1 \ \mu F$
- Internal current and thermal limit
- Available in DFN6 (2x2), DFN6 (3x3) mm, SO8-batwing and PPAK packages
- Temperature range: -40 °C to 125 °C
- Reverse current protection
- Output discharge function (optional)

Applications

- Consumer
- Computer
- Battery-powered systems
- Low voltage point-of-load
- USB-powered devices

Description

The LDL112 is a low-dropout linear regulator, which can provide a maximum current of 1.2 A, with a typical dropout voltage of 300 mV.

It is stabilized with a ceramic capacitor on the output.

The very low drop voltage, low quiescent current and reverse current protection features make it suitable for low power battery-powered applications.

The enable logic control function puts the LDL112 in shutdown mode allowing a total current consumption lower than 1 μ A.

The device is equipped with current limit and thermal protection.

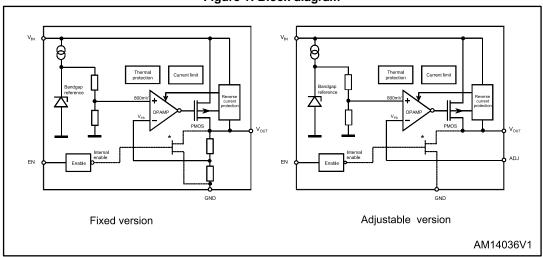
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LDL112 Diagram

1 Diagram

Figure 1: Block diagram





(*) The output discharge function is optional.

Pin configuration LDL112

2 Pin configuration

Figure 2: Pin connection DFN6 (3x3) and DFN6 (2x2) (top view)

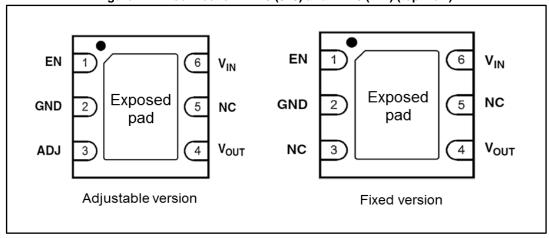


Figure 3: Pin connection PPAK and SO8 (top view)

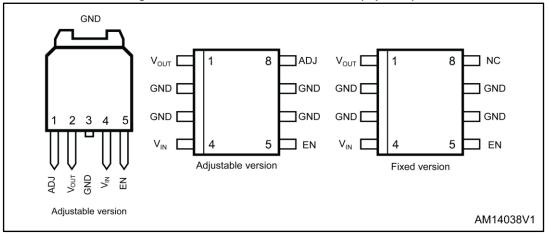


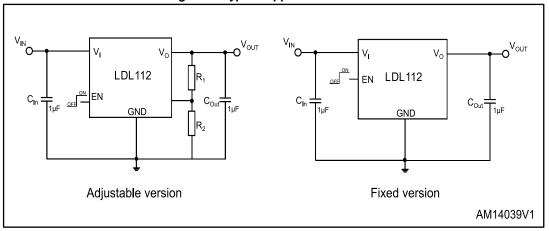
Table 1: Pin description

Symbol	Function		
V _{IN}	LDO input voltage		
GND	Common ground		
EN	Enable pin logic input: low = shutdown, high = active		
ADJ Adjustable pin (on adjustable version)			
Vout LDO output voltage			
Exposed pad Must be connected to GND			
NC	Not connected		

LDL112 Typical application

3 Typical application

Figure 4: Typical application circuits



Maximum ratings LDL112

4 Maximum ratings

Table 2: Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{IN}	DC input voltage	- 0.3 to 7	V
V _{OUT}	DC output voltage	- 0.3 to V _I + 0.3	V
V _{EN}	Enable input voltage	- 0.3 to V _I + 0.3	V
V _{ADJ}	ADJ pin voltage	2	V
l _{out}	Output current	Internally limited	mA
PD	Power dissipation	Internally limited	mW
Tstg	Storage temperature range	- 65 to 150	°C
Тор	Operating junction temperature range	- 40 to 125	°C



Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. All values are referred to GND.

Table 3: Thermal data

Symbol	Parameter	DFN6 (3x3)	DFN6 (2x2)	SO8	PPAK	Unit
R_{thJA}	Thermal resistance junction-ambient	55	65	55 ⁽¹⁾	100	°C/W
RthJC	Thermal resistance junction-case	10	15	20	8	°C/W

Notes:

⁽¹⁾Considering 6 cm² of copper board heatsink.

LDL112 Electrical characteristics

5 Electrical characteristics

 $T_{J}=25~^{\circ}C,~V_{IN}=V_{OUT(NOM)}+0.5~V~(for~V_{OUT(NOM)}\leq 1~V,~V_{IN}=2.1~V),~C_{IN}=C_{OUT}=1~\mu F,\\ I_{OUT}=5~mA,~V_{EN}=V_{IN},~unless~otherwise~specified.$

Table 4: LDL112 electrical characteristics (fixed version)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
Vin	Operating input voltage		1.6		5.5	V
Va=	Vaur goourgov	I _{OUT} = 5 mA, T _J = 25 °C	-2.0		2.0	%
Vouт	V _{оит} accuracy	I _{OUT} = 5 mA, -40 °C < T _J < 125 °C	-3.0		3.0	%
ΔVουτ	Static line regulation (1)	$V_{OUT(NOM)} + 0.5 \text{ V} < V_{IN} \le 5.5 \text{ V}$ (2)		0.05	0.1	%/V
ΔVουτ	Static load regulation	I _{OUT} = 0 mA to 1.2 A, V _{IN} > 2.1 V		15	30	mV
		Iout = 1 A, Vout = 3.3 V		300		
V _{DROP}	Dropout voltage (3)	IOUT = 1.2 A, VOUT = 3.3 V 40 °C < T _J < 125 °C		350	600	mV
ем	Output noise voltage	10 Hz to 100 kHz, I _{OUT} = 10 mA		135		μV _{RMS}
SVR	Supply voltage rejection	$V_{IN} = V_{OUT(NOM)} + 0.5 \text{ V}^{(2)}$ +/- V_{RIPPLE} $V_{RIPPLE} = 0.2 \text{ V}$ $f_{IPPLE} = 0.2 \text{ KHz}$, $f_{OUT} = 10 \text{ mA}$		57		dB
		I _{OUT} = 0 mA,-40 °C < T _J <125 °C		35	70	
IQ	Quiescent current	I _{OUT} = 1.2 A, V _{OUT(NOM)} + 1 V ⁽²⁾ 40 °C < T _J < 125 °C		250	400	μA
		V_{IN} input current in off mode: $V_{EN} = GND$		0.1	1	
Isc	Short-circuit current	$R_L = 0, V_{IN} > 2.1 V$	1.4	2		Α
V _{EN}	Enable input logic low	$V_{IN} = V_{OUT(NOM)} + 0.5 \text{ V}^{(2)} \text{ to } 5.5 \text{ V},$ -40 °C < T _J < 125 °C			0.35	V
VEN	Enable input logic high	V _{IN} = V _{OUT(NOM)} + 0.5 V ⁽²⁾ to 5.5 V -40 °C < T _J < 125 °C	1.4			V
IEN	Enable pin input current	VEN = VIN			100	nA
Tourse	Thermal shutdown			165		°C
Tshdn	Hysteresis			20		C
Соит	Output capacitor	Capacitance (see Section 7: "Typical performance characteristics")	1		10	μF

Notes:

 $^{^{(1)}}Not$ applicable for $V_{out(nom)} > 4.5 \ V.$

 $^{^{(2)}} For \ V_{OUTNOM}$ lower than or equal to 1 V, V_{IN} = 2.1 V.

⁽³⁾Dropout voltage is the input-to-output voltage difference at which the output voltage is 100 mV below its nominal value.

Electrical characteristics LDL112

 T_J = 25 °C, V_{IN} = 2.1 V, C_{IN} = C_{OUT} = 1 $\mu F,\ I_{OUT}$ = 5 mA, V_{EN} = $V_{IN},\ unless$ otherwise specified.

Table 5: LDL112 electrical characteristics (adjustable version)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
Vin	Operating input voltage		1.6		5.5	V
V	V 000Ur00V	I _{ОUТ} = 5 mA, T _J = 25 °C	784	800	816	mV
V_{ADJ}	V _{ADJ} accuracy	I _{OUT} = 5 mA, -40 °C < T _J < 125 °C	-3.0		3.0	%
ΔVουτ	Static line regulation	$2.1 \text{ V} \stackrel{(2)}{\sim} \leq V_{\text{IN}} \leq 5.5 \text{ V},$ $I_{\text{OUT}} = 1 \text{ mA}$		0.05	0.1	%/V
ΔV_{OUT}	Static load regulation	I _{OUT} = 0 mA to 1.2 A,V _{IN} > 2.1 V		6	20	mV
		Іоит = 1 A, V _{оит} = 3.3 V		300		
V _{DROP}	Dropout voltage (3)	I _{OUT} = 1.2 A,V _{OUT} = 3.3 V 40 °C < T _J < 125 °C		350	600	mV
e _N	Output noise voltage	10 Hz to 100 kHz, I _{OUT} = 10 mA		60		μV_{RMS}
I _{ADJ}	Adjust pin current			0.130	1	μA
SVR	Supply voltage rejection	$V_{IN} = V_{OUTNOM} + 0.5 \text{ V}^{(2)} + /-V_{RIPPLE} V_{RIPPLE} = 0.2 \text{ V}$ frequency = 1 kHz lout = 10 mA		53		dB
	Quiescent current	Iоит = 0 mA,-40 °C < T _J < 125 °C		35	70	
lα		Iout = 1.2 A, 2.1 V < V _{IN} < 5.5 V, -40 °C < T _J < 125 °C		240	400	μΑ
		V _{IN} input current in off mode: V _{EN} = GND		0.1	1	
Isc	Short-circuit current	R _L = 0, V _{IN} > 2.1 V	1.4	2		Α
.,	Enable input logic low	V _{IN} = 2 V ⁽²⁾ to 5.5 V, -40 °C < T _J < 125 °C		0	0.35	
Ven	Enable input logic high	V _{IN} = 2 V ⁽²⁾ to 5.5 V, -40 °C < T _J < 125 °C	1.4			V
I _{EN}	Enable pin input current	Ven = Vin			100	nA
_	Thermal shutdown			165		°C
T _{SHDN}	Hysteresis			20		
Соит	Output capacitor	Capacitance (see Section 7: "Typical performance characteristics")	1		10	μF

Notes:

 $^{^{(1)}}$ Not applicable for $V_{out(nom)} > 4.5 \text{ V}$.

 $^{^{(2)}}$ For V_{OUT} lower than or equal to 1 V, V_{IN} = 2.1 V.

 $^{^{(3)}}$ Dropout voltage is the input-to-output voltage difference at which the output voltage is 100 mV below its nominal value.

6 Application information

6.1 Thermal and short-circuit protections

The LDL112 is self-protected from short-circuit condition and overtemperature. When the output load is higher than the one supported by the device, the output current increases until the limit of typically 2 A is reached, at this point the current is kept constant even when the load impedance is zero.

Thermal protection acts when the junction temperature reaches 165 °C, therefore the IC shuts down. As soon as the junction temperature falls again below the thermal hysteresis value the device starts working again.

In order to calculate the maximum power that the device can dissipate, keeping the junction temperature below the T_{OP} , the following formula is used:

Equation 1

$$P_{DMAX} = (125 - T_{AMB})/R_{THJA}$$

6.2 Output voltage setting for ADJ version

In the adjustable version, the output voltage can be set from 0.8 V up to the input voltage minus the voltage drop across the pass transistor (dropout voltage), by connecting a resistor divider between the ADJ pin and the output, thus allowing remote voltage sensing.

The resistor divider could be selected by the following equation:

Equation 2

$$V_{OUT} = V_{ADJ} (1 + R1 / R2)$$
, with $V_{ADJ} = 0.8 V (typ.)$

It is recommended to use resistors with values in the range of 10 k Ω to 50 k Ω . Lower values can also be suitable, but current consumption increases.

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6.3 Reverse current protection

The device avoids the reverse current to flow from output to input during any operating condition (with enable pin in high or low status). The reverse current protection acts in particular during fast turning on/off operations or when another power supply (with higher voltage than the input one) is connected to the output port. If a power supply with lower voltage than the LDO output voltage is connected to V_{OUT} pin, LDO enters the current protection status, causing high power dissipation.

In the application, the LDL112 reverse current protection acts in the following cases:

- Off-state, EN pin is at GND level, V_{OUT} > [V_{IN} + 100 mV]. In this case the device power pass element (MOSFET) is off, the bulk and gate are switched to V_{OUT} and therefore all possible current paths from V_{OUT} to V_{IN} are interrupted.
- 2. On-state, EN pin is at high level and V_{OUT} > V_{OUT(nominal)}. In this condition, V_{OUT} is higher than the nominal level, so the device op-amp works in open loop and the power element is off. V_{GS} is zero, the bulk and gate are switched to V_{OUT} (where V_{OUT} > [V_{IN} + 100 mV]) therefore all possible current paths from V_{OUT} to V_{IN} are interrupted.
- 3. On-state, EN pin is at high level and V_{OUT}< V_{OUT(nominal)}. In this condition V_{OUT} is lower than the nominal level, so the op-amp works in open loop with the power MOSFET on. V_{GS} is maximal so the power channel conducts with very low R_{DS(on)}. When V_{OUT} > V_{IN} the current can flow from V_{OUT} to V_{IN} until the condition V_{OUT} > (V_{IN} + 100 mV) is reached.

7 Typical performance characteristics

($C_{IN} = C_{OUT} = 1 \mu F$, V_{EN} to V_{IN} , $T = 25 \,^{\circ}C$ unless otherwise specified)

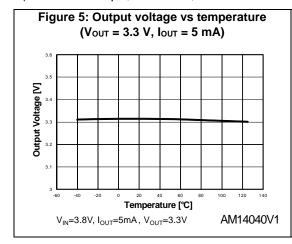
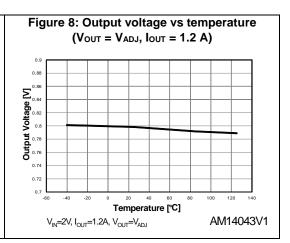
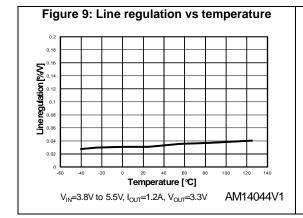


Figure 7: Output voltage vs temperature
(Vout = Vadd, lout = 5 mA)

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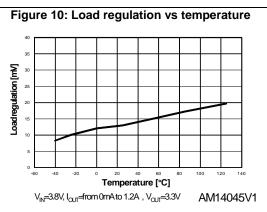


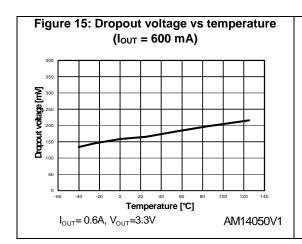
Figure 11: Quiescent current vs temperature (lout = 0 mA)

Figure 12: Quiescent current vs temperature (I_{OUT} = 1.2 A)

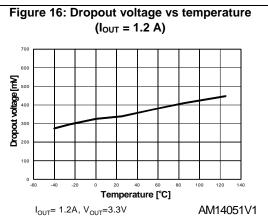
Figure 13: Shutdown current vs temperature

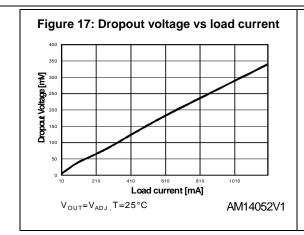
Figure 14: Quiescent current vs load current

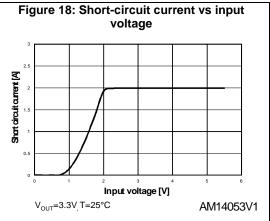
| VIN=2V, VOUT=VADJ, T=25°C AM14049V1

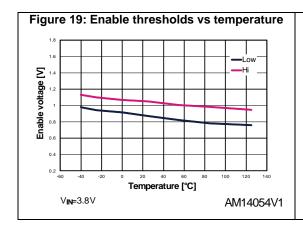


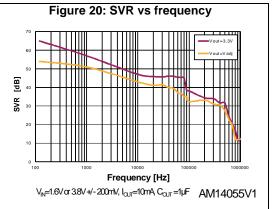
12/32

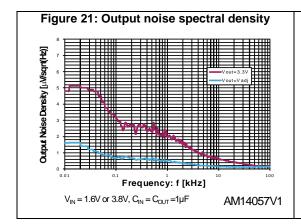


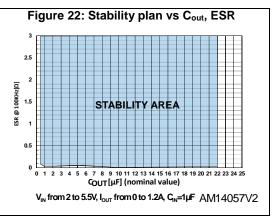


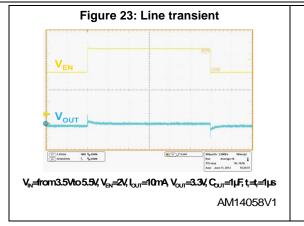


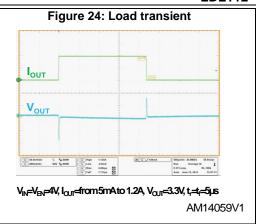


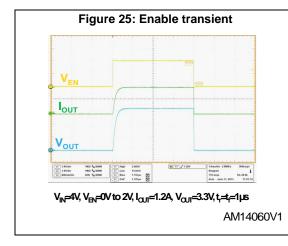


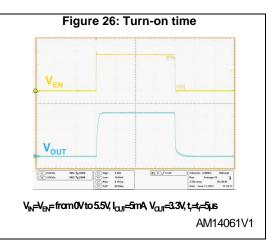












8 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

8.1 DFN6 (3x3) package information

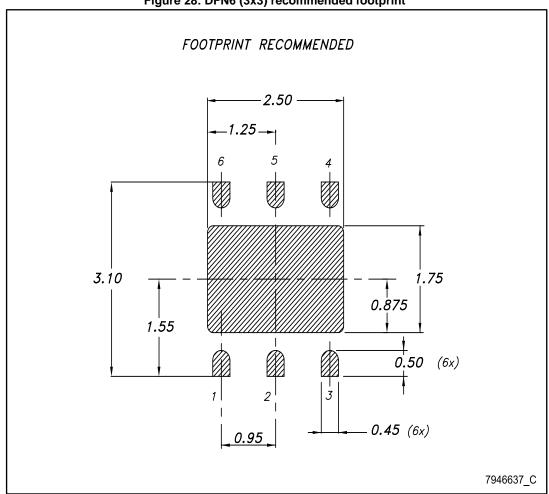
BOTTOM VIEW D2 EXPOSED PAD PIN 1 ID **b** (6x) // 0.1 C A3 SEATING PLANE A1 c 0.08 C LEADS COPLANARITY E/2PIN 1 ID D/2-OP VIEW 7946637_C

Figure 27: DFN6 (3x3) package outline

Table 6: DFN6 (3x3) mechanical data

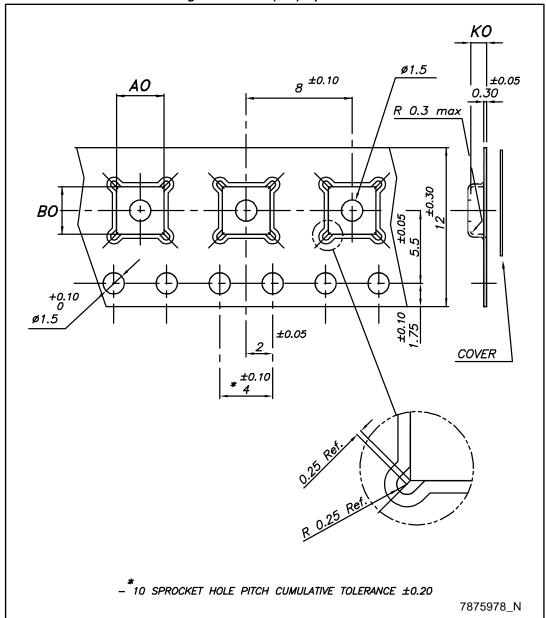
Dim.	mm			
Dilli.	Min.	Тур.	Max.	
А	0.80		1	
A1	0	0.02	0.05	
A3		0.20		
b	0.23		0.45	
D	2.90	3	3.10	
D2	2.23		2.50	
E	2.90	3	3.10	
E2	1.50		1.75	
е		0.95		
L	0.30	0.40	0.50	

Figure 28: DFN6 (3x3) recommended footprint



8.2 DFN6 (3x3) packing information

Figure 29: DFN6 (3x3) tape outline



Package information LDL112

Figure 30: DFN6 (3x3) reel outline

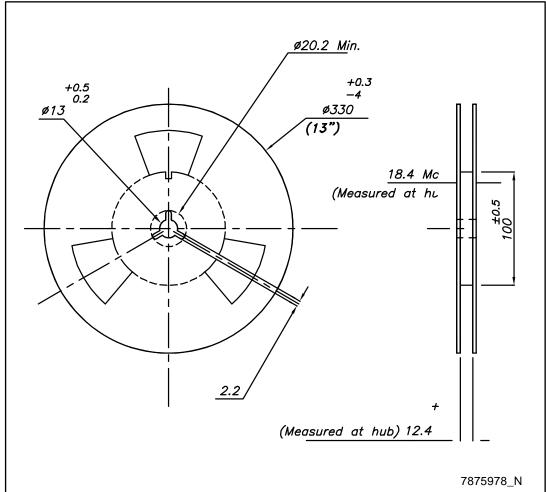


Table 7: DFN6 (3x3) tape and reel mechanical data

Dim.		mm	
Dilli.	Min.	Тур.	Max.
A0	3.20	3.30	3.40
В0	3.20	3.30	3.40
K0	1	1.10	1.20

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8.3 DFN6 (2x2) package information

Figure 31: DFN6 (2x2) package outline

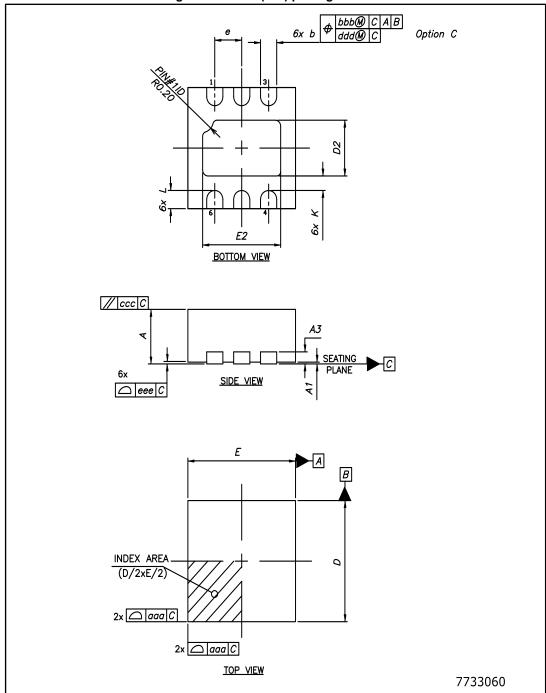


Table 8: DFN6 (2x2) mechanical data

Table 6. Bi No (EXZ) moonamen aaa					
Dim.		mm			
Dilli.	Min.	Тур.	Max.		
Α	0.70	0.75	0.80		
A1	0.00	0.02	0.05		
А3	-	0.203 ref	-		
b	0.25	0.30	0.35		
D	-	2.00	-		
E	-	2.00	-		
е	-	0.50	-		
D2	0.77	0.92	1.02		
E2	1.30	1.45	1.55		
K	0.15	-	-		
L	0.20	0.30	0.40		
aaa	-	0.05	-		
bbb	-	0.10	-		
ccc	-	0.10	-		
ddd	-	0.05	-		
eee	-	0.08	-		

Figure 32: DFN6 (2x2) recommended footprint

Package information LDL112

8.4 DFN6 (2x2) packing information

Figure 33: DFN6 (2x2) reel outline

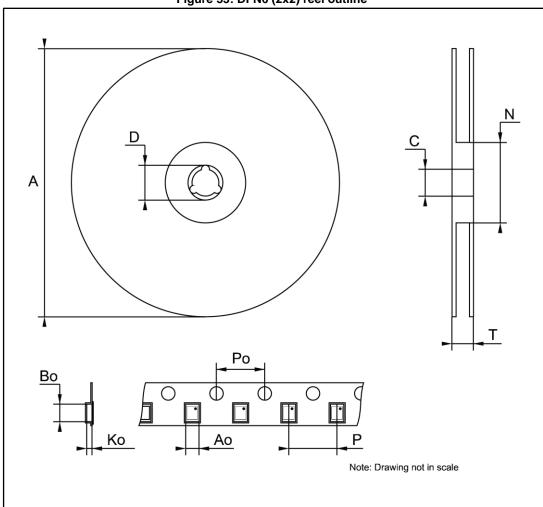


Table 9: DFN6 (2x2) tape and reel mechanical data

Dim.	, , 1	mm	
Dilli.	Min.	Тур.	Max.
А			180
С	12.8		13.2
D	20.2		
N	60		
Т			14.4
A0		2.4	
В0		2.4	
K0		1.3	
P0		4	
Р		4	

8.5 SO8-batwing package information

Figure 34: SO-8 batwing package outline

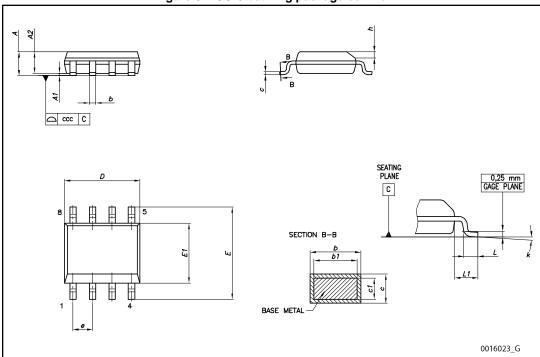


Table 10: SO-8 batwing mechanical data

Dim		mm	
Dim.	Min.	Тур.	Max.
A			1.75
A1	0.10		0.25
A2	1.25		
b	0.31		0.51
b1	0.28		0.48
С	0.10		0.25
c1	0.10		0.23
D	4.80	4.90	5.00
Е	5.80	6.00	6.20
E1	3.80	3.90	4.00
е		1.27	
h	0.25		0.50
L	0.40		1.27
L1		1.04	
L2		0.25	
k	0°		8°
ccc			0.10

Package information LDL112

Figure 35: SO-8 batwing recommended footprint

O.6 (x8)

O.6 (x8)

O.6 (x8)

O.6 (x8)

O.7 (x8)

O.8 (x8)

O.9 (x8)

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8.6 SO8-batwing packing information

Figure 36: SO8-batwing tape and reel outline

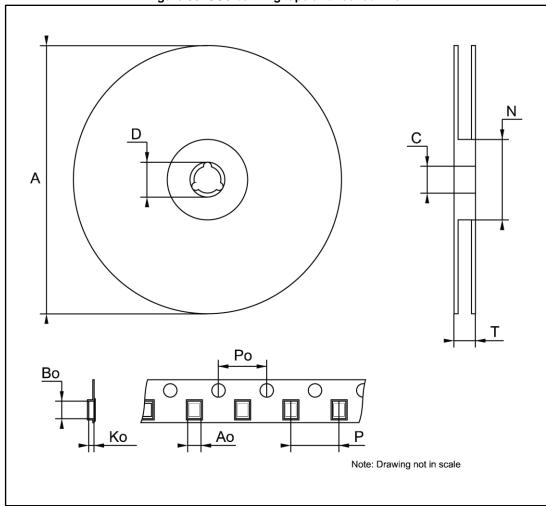


Table 11: SO8-batwing mechanical data

Dim.		mm	
Dim.	Min.	Тур.	Max.
А			330
С	12.8		13.2
D	20.2		
N	60		
Т			22.4
A0	8.1		8.5
В0	5.5		5.9
K0	2.1		2.3
P0	3.9		4.1
Р	7.9		8.1

Package information LDL112

8.7 PPAK package information

Figure 37: PPAK package outline

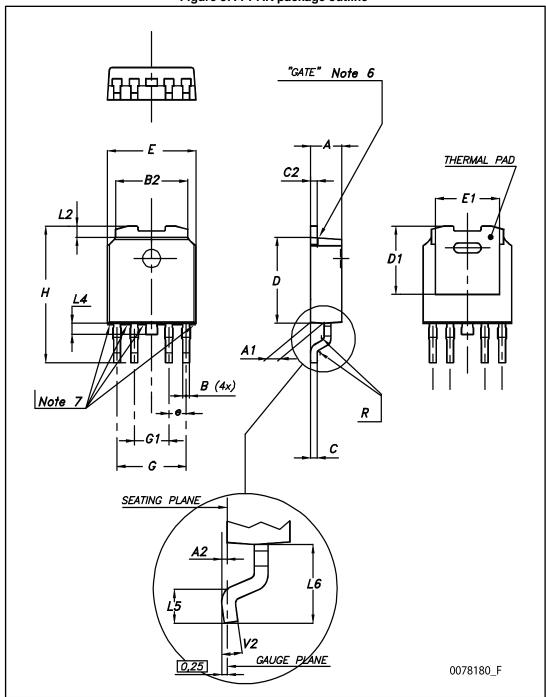


Table 12: PPAK mechanical data

Dim.	mm			
	Min.	Тур.	Max.	
A	2.2		2.4	
A1	0.9		1.1	
A2	0.03		0.23	
В	0.4		0.6	
B2	5.2		5.4	
С	0.45		0.6	
C2	0.48		0.6	
D	6		6.2	
D1		5.1		
Е	6.4		6.6	
E1		4.7		
е		1.27		
G	4.9		5.25	
G1	2.38		2.7	
Н	9.35		10.1	
L2		0.8	1	
L4	0.6		1	
L5	1			
L6		2.8		
R		0.20		
V2	0°		8°	

Package information LDL112

8.8 PPAK packing information

Figure 38: PPAK tape outline

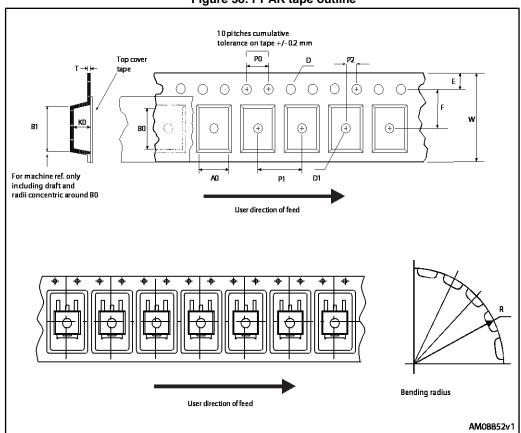


Figure 39: PPAK reel outline

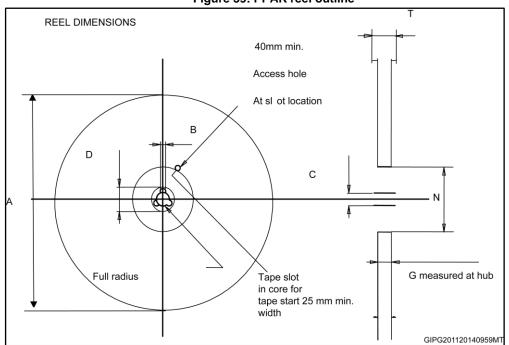


Table 13: PPAK mechanical data

	Таре		Reel			
Dim.	mm		Dim	r	mm	
	Min.	Max.	Dim.	Min.	Max.	
A0	6.8	7	А		330	
В0	10.4	10.6	В	1.5		
B1		12.1	С	12.8	13.2	
D	1.5	1.6	D	20.2		
D1	1.5		G	16.4	18.4	
E	1.65	1.85	N	50		
F	7.4	7.6	Т		22.4	
K0	2.55	2.75				
P0	3.9	4.1	Bas	e qty.	2500	
P1	7.9	8.1	Bas	e qty.	2500	
P2	1.9	2.1				
R	40					
Т	0.25	0.35				
W	15.7	16.3				

Ordering information LDL112

9 Ordering information

Table 14: Order codes

DFN6 (3x3)	DFN6 (2x2)	SO8-batwing	PPAK	Output voltage (V)
LDL112PV10R	LDL112PU10R	LDL112D10R		1.0
LDL112PV12R	LDL112PU12R	LDL112D12R		1.2
LDL112PV15R	LDL112PU15R	LDL112D15R		1.5
LDL112PV18R	LDL112PU18R	LDL112D18R		1.8
LDL112PV25R	LDL112PU25R	LDL112D25R		2.5
LDL112PV30R	LDL112PU30R	LDL112D30R		3.0
LDL112PV33R	LDL112PU33R	LDL112D33R		3.3
LDL112PVR	LDL112PUR	LDL112DR	LDL112PT-TR	Adj

LDL112 Revision history

10 Revision history

Table 15: Document revision history

Date	Revision	Changes
21-Nov-2014	1	Initial release.
28-Oct-2016	2	Updated Figure 31: "DFN6 (2x2) package outline". Modified Table 14: "Order codes". Minor text changes.

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